NSN 5961-00-078-5303

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View Online at https://aerobasegroup.com/nsn/5961-00-078-5303 **Inclosure Material:** Glass and metal **Overall Length:** 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 forward voltage, peak **Current Rating Per Characteristic:** 1.25 amperes source cutoff current preset **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 18876-10106193 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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